

<b>SANYO</b>	No. 1012A	<b>2SC3089</b>
NPN Triple Diffused Planar Silicon Transistor		
FOR SWITCHING REGULATORS		

**Features**

- . High breakdown voltage ( $V_{CBO} \geq 800V$ )
- . Fast switching speed.
- . Wide ASO.

**Absolute Maximum Ratings at  $T_a=25^\circ C$**

Parameter	Symbol	Value	unit
Collector-to-Base Voltage	$V_{CBO}$	800	V
Collector-to-Emitter Voltage	$V_{CEO}$	500	V
Emitter-to-Base Voltage	$V_{EBO}$	7	V
Collector Current	$I_C$	7	A
Peak Collector Current	$i_{cp}$	14	A
		PW $\leq$ 300 $\mu$ s, Duty Cycle $\leq$ 10%	
Base Current	$I_B$	3	A
Collector Dissipation	$P_C$	2.5	W
		$T_c=25^\circ C$	
Junction Temperature	$T_j$	80	W
Storage Temperature	$T_{stg}$	150	$^\circ C$
		-55 to +150	$^\circ C$

**Electrical Characteristics at  $T_a=25^\circ C$**

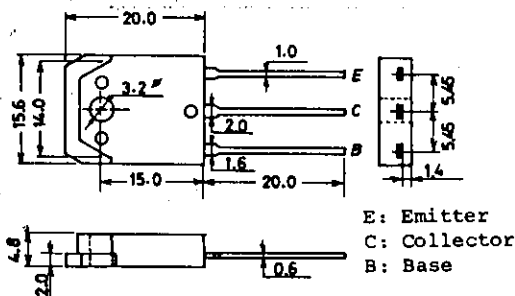
Parameter	Symbol	Test Conditions	min	typ	max	unit
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=500V, I_E=0$			10	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=5V, I_C=0$			10	$\mu A$
DC Current Gain	$h_{FE}(1)$	$V_{CE}=5V, I_C=0.6A$	15*		50*	
	$h_{FE}(2)$	$V_{CE}=5V, I_C=3A$	8			
C-E Saturation Voltage	$V_{CE(sat)}$	$I_C=3A, I_B=0.6A$			1.0	V
B-E Saturation Voltage	$V_{BE(sat)}$	$I_C=3A, I_B=0.6A$			1.5	V
Gain-Bandwidth Product	$f_T$	$V_{CE}=10V, I_C=0.6A$		18		MHz
Output Capacitance	$c_{ob}$	$V_{CB}=10V, f=1MHz$		80		pF
C-B Breakdown Voltage	$V_{(BR)CBO}$	$I_C=1mA, I_E=0$	800			V
C-E Breakdown Voltage	$V_{(BR)CEO}$	$I_C=5mA, R_{BE}=\infty$	500			V
E-B Breakdown Voltage	$V_{(BR)EBO}$	$I_E=1mA, I_C=0$	7			V
C-E Sustain Voltage	$V_{CEO(sus)}$	$I_C=7A, I_B=0.14A, L=50\mu H$	500			V
C-E Sustain Voltage	$V_{CEX(sus)}$	$I_C=7A, I_{B1}=0.14A, L=200\mu H,$ $I_{B2}=-0.14A, \text{clamped}$	500			V
C-E Sustain Voltage	$V_{CEX(sus)}$	$I_C=1.2A, I_{B1}=0.24A, L=200\mu H,$ $I_{B2}=-0.24A, \text{clamped}$	550			V

\*: The  $h_{FE}(1)$  of the 2SC3089 is classified as follows. When specifying the  $h_{FE}(1)$  rank, specify two ranks or more in principle.

15	L	30	20	M	40	30	N	50
----	---	----	----	---	----	----	---	----

Continued on next page.

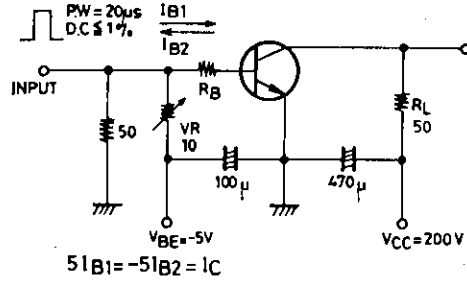
**Package Dimensions 2022**  
(unit: mm)



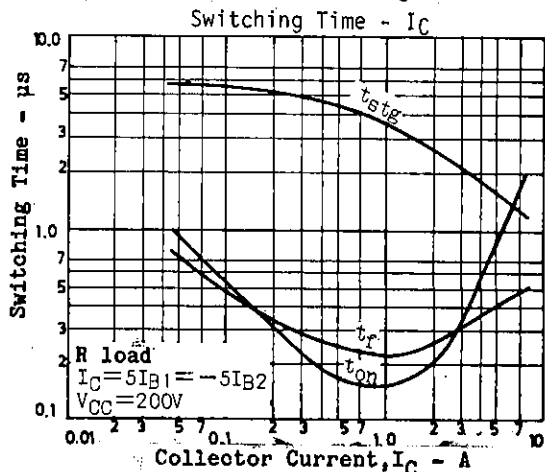
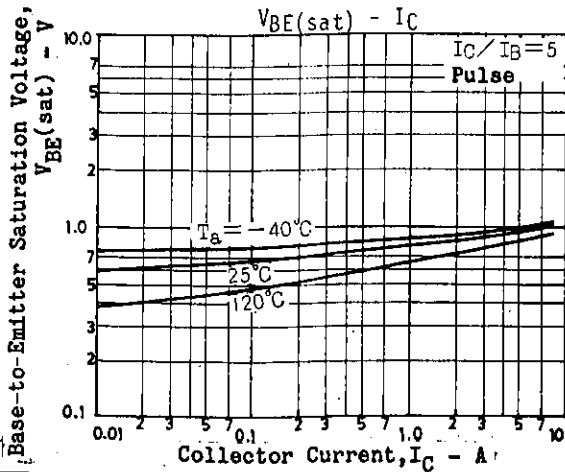
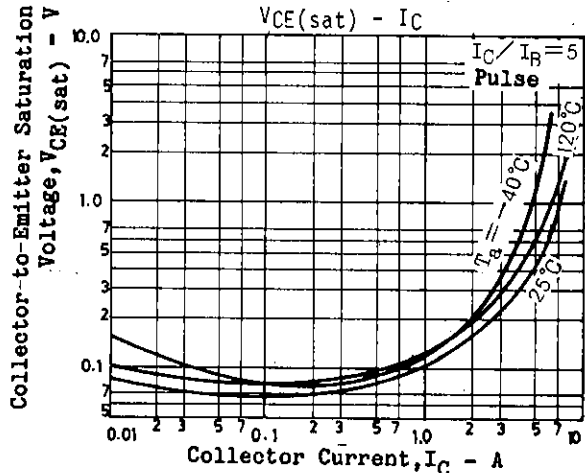
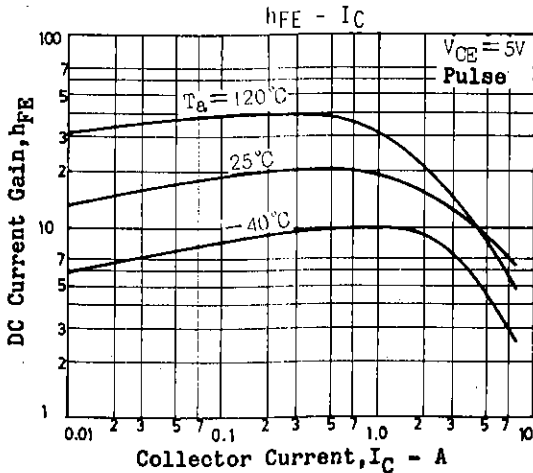
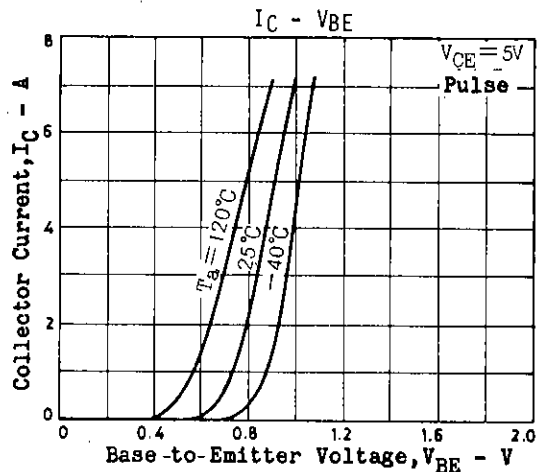
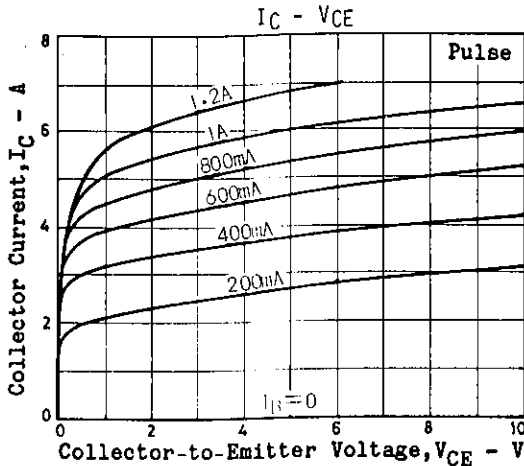
Continued from preceding page.

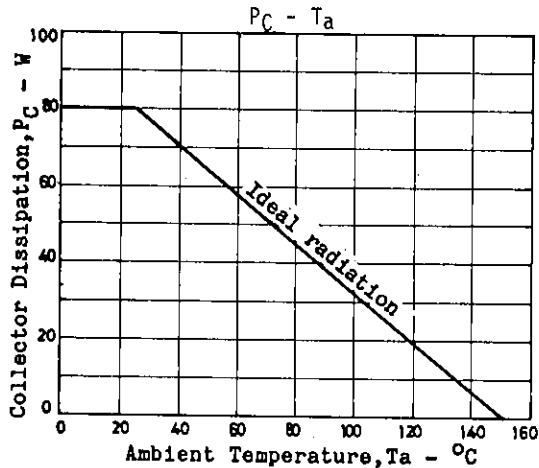
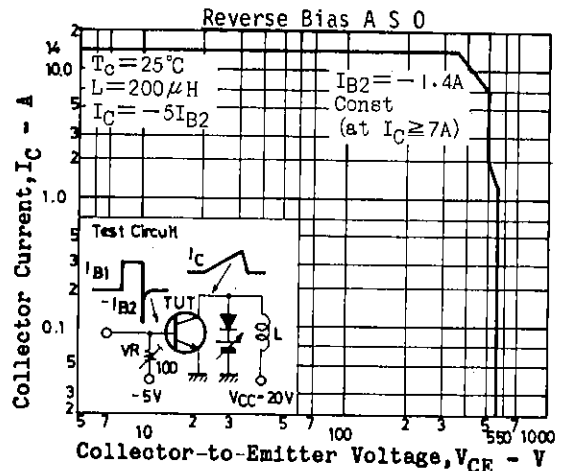
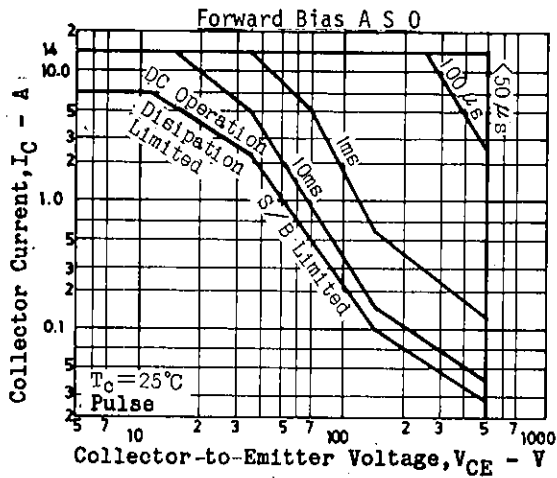
			min	typ	max	unit
Turn-ON Time	$t_{on}$	$I_C=4A, I_{B1}=0.8A, I_{B2}=-0.8A,$			1.0	$\mu s$
		$R_L=50ohms, V_{CC}=200V$				
Storage Time	$t_{stg}$	" "			3.0	$\mu s$
Fall Time	$t_f$	" "			1.0	$\mu s$

Switching Time Test Circuit



Unit (Resistance :  $\Omega$ , Capacitance : F)





- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
  - ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use;
  - ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.